

Radiation-Hard Optical links for detector readout

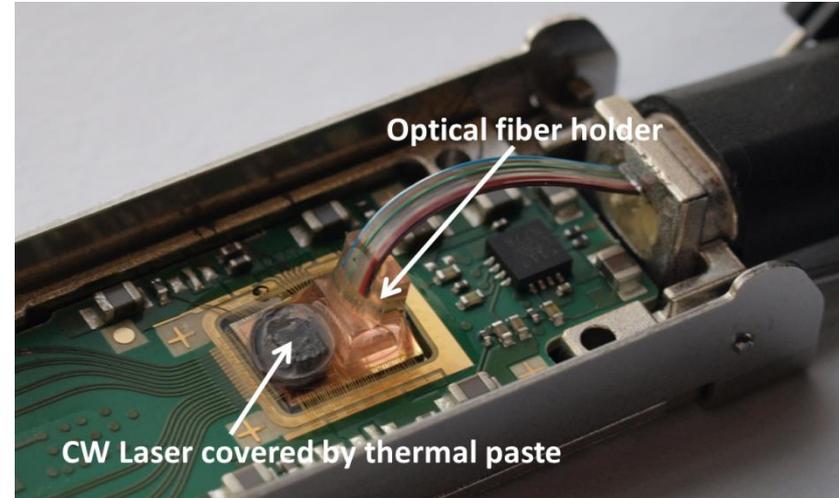
A. Paramonov for ANL group

16 July 2020

Snowmass TDAQ Subgroup meeting

Lol overview

- Argonne has characterized radiation tolerance of commercial Si-photonics optical transceivers for the ATLAS experiment at the LHC. Other institutions (e.g. CERN) have also looked at the technology.
 - The optical components were found to be highly radiation tolerant.
- Target: TID~ 3 Mrad, NIEL~ $1e17$ n/cm², 10-50 Gbps/fiber.
- The Si-photonics approach allows fabrication high-speed, low-cost, low-power, high-reliability, and low-BER fiber-optical transceivers
- Si-photonics utilizes fabrication of optical circuits in the same wafer as electrical circuits using conventional CMOS processes. → “Fiber to chip” instead of copper cable
- E.G. The technology could significantly reduce the mass, complexity, and power consumption of the ATLAS inner tracker while also improving its performance.
- The HEP community could benefit from further adopting the technology through partnership with commercial companies or by developing our own devices and expertise. The Si-photonics device libraries are widely available.

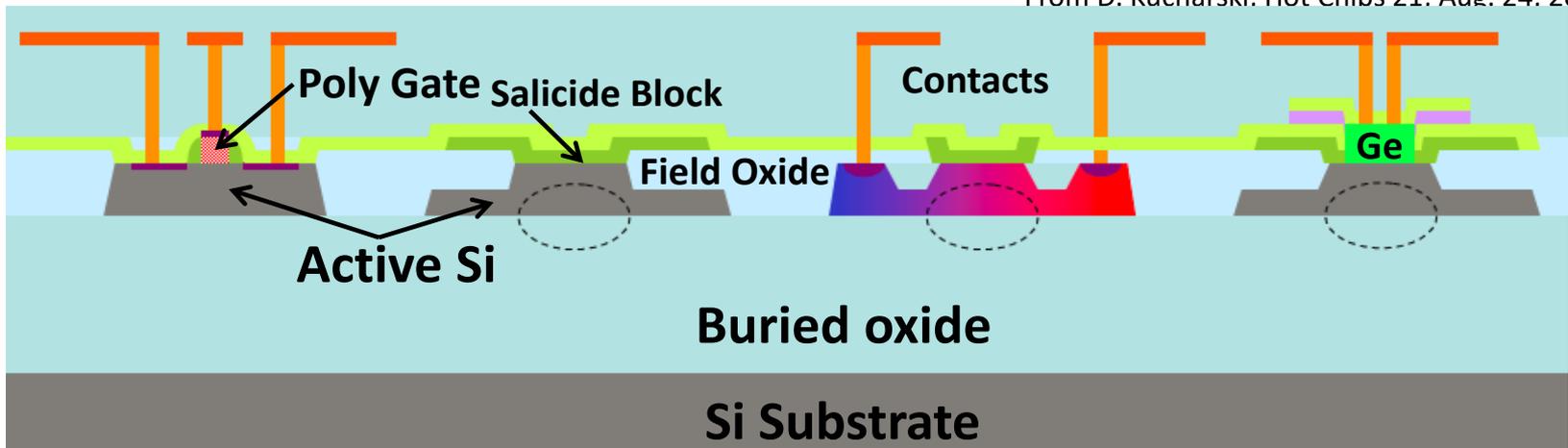


BACKUP

Si photonics technology uses a commercial CMOS SOI process (see 10.1109/JSSC.2007.908713 or 10.1109/OFC.2008.4528356). The optical elements are:

- Passive waveguides (losses < 0.1 dB/cm) → interconnects between other optical devices.
 - Utilize the high index of refraction between Si and SiO₂.
- Phase modulators → Used in the MZI-based amplitude modulators
 - The refractive index of Si depends on the free carrier density (electrons and holes)
 - Implemented as a PN diode structure by using implants
 - Bias the PN diode to change the phase
- High-speed photo detectors
 - Selective growth of Ge on top of the Si waveguide.
- Low-loss grating couplers, holographic lens (efficiency ~ 95%)
 - Used to couple light in and out of the Si die
 - Redirect light from horizontal direction (die) to vertical (fiber)

From D. Kucharski. Hot Chips 21. Aug. 24. 2009



Transistor



Waveguide



Phase Modulator



Photo-Detector